APT70GR65B2SCD30 Information

Part Number	APT70GR65B2SCD30
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Description	INSULATED GATE BIPOLAR TRANSISTO
Package	TO-247-3

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

For Reference Only

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

APT70GR65B2SCD30 Specifications

Manufacturer Part Number	APT70GR65B2SCD30
Manufacturer	Microsemi Corporation
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-247-3
Series	*
IGBT Type	NPT
Voltage - Collector Emitter Breakdown (Max)	650V
Current - Collector (Ic) (Max)	134A
Current - Collector Pulsed (Icm)	260A
Vce(on) (Max) @ Vge, Ic	2.4V @ 15V, 70A
Power - Max	595W
Switching Energy	-
Input Type	-
Gate Charge	305nC
Td (on/off) @ 25°C	19ns/170ns
Test Condition	433V, 70A, 4.3 Ohm, 15V
Reverse Recovery Time (trr)	-
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-247-3
Supplier Device Package	T-MAX? [B2]
	Report errors?

APT70GR65B2SCD30 Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

APT70GR65B2SCD30 Payment Methods

APT70GR65B2SCD30 Shipping Methods

If you have any question about APT70GR65B2SCD30, please do not hesitate to contact us!
Website: https://www.heisener.com
E-mail: salesdept@heisener.com